

INVERTER

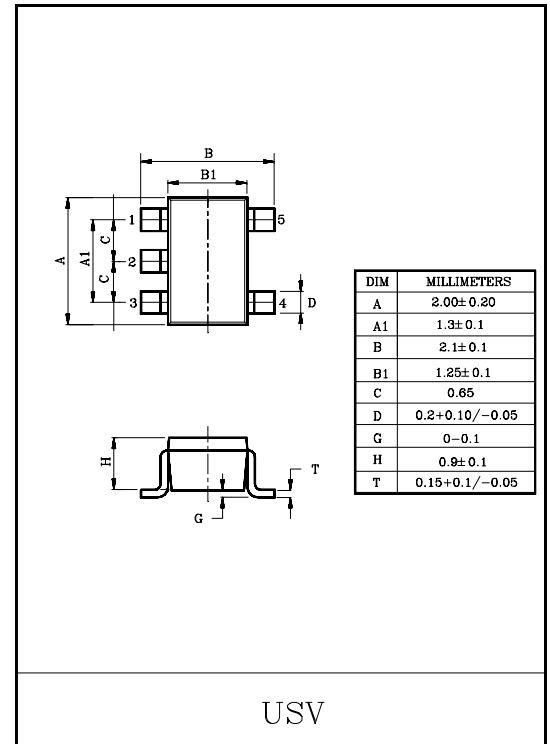
The KIC7S04FU is a high speed C²MOS INVERTER fabricated with silicon gate C²MOS technology. It achieves high speed operation similar to equivalent LSTTL while maintaining the C²MOS low power dissipation. The internal circuit is composed of 3 stages including buffer output, which enables high noise immunity and stable output. The inputs is equipped with protection circuits against static discharge or transient excess voltage.

FEATURES

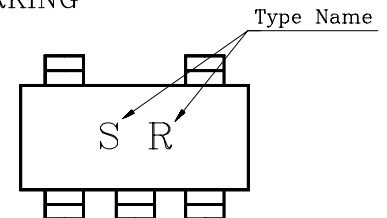
- High Speed : $t_{pd}=7ns$ (Typ.) at $V_{CC}=5V$.
- Low Power Dissipation : $I_{CC}=1\mu A$ (Max.) at $T_a=25^{\circ}C$.
- High Noise Immunity : $V_{NIH}=V_{NIL}=28\% V_{CC}$ (Min.).
- Output Drive Capability : 5 LSTTL Loads.
- Symmetrical Output Impedance : $|I_{OH}|=I_{OL}=2mA$ (Min.)
- Balanced Propagation Delays : $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range : $V_{CC(opr)}=2\sim 6V$.

MAXIMUM RATINGS

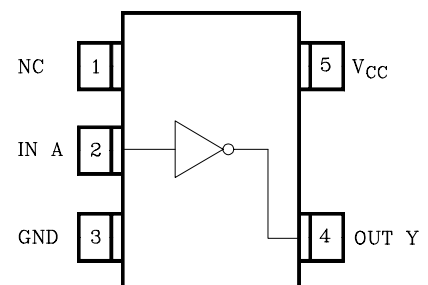
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	$-0.5\sim 7$	V
DC Input Voltage	V_{IN}	$-0.5\sim V_{CC}+0.5$	V
DC Output Voltage	V_{OUT}	$-0.5\sim V_{CC}+0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 12.5	mA
DC V_{CC} /Ground Current	I_{CC}	± 25	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	$-65\sim 150$	$^{\circ}C$
Lead Temperature (10s)	T_L	260	$^{\circ}C$



MARKING



PIN CONNECTION(TOP VIEW)



KIC7S04FU

CIRCUIT DIAGRAM



RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~ V_{CC}	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	t_r, t_f	0~1000 ($V_{CC}=2.0V$) 0~500 ($V_{CC}=4.5V$) 0~400 ($V_{CC}=6.0V$)	ns

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta=25°C			Ta=-40~85°C		UNIT
				V_{CC}	MIN.	TYP.	MAX.	MIN.	MAX.
High-Level Input Voltage	V_{IH}	-		2.0 4.5 6.0	1.5 3.15 4.2	- - -	- - -	1.5 3.15 4.2	V
Low-Level Input Voltage	V_{IL}	-		2.0 4.5 6.0	- - -	- - -	0.5 1.35 1.8	- - -	V
High-Level Output Voltage	V_{OH}	$V_{IN}=V_{IL}$	$I_{OH}=-20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	- - -	1.9 4.4 5.9	V
			$I_{OH}=-2mA$	4.5 6.0	4.18 5.68	4.31 5.80	- -	4.13 5.63	
			$I_{OH}=-2.6mA$	6.0	5.68	5.80	-	5.63	
Low-Level Output Voltage	V_{OL}	$V_{IN}=V_{IH}$	$I_{OL}=20\mu A$	2.0 4.5 6.0	- - -	0.0 0.0 0.0	0.1 0.1 0.1	- - -	V
			$I_{OL}=2mA$	4.5 6.0	- -	0.17 0.18	0.26 0.26	- -	
			$I_{OL}=2.6mA$	6.0	-	0.18	0.26	-	
Input Leakage Current	I_{IN}	$V_{IN}=V_{CC}$ or GND		6.0	-	-	± 0.1	-	μA
Quiescent Supply Current	I_{CC}	$V_{IN}=V_{CC}$ or GND		6.0	-	-	1.0	-	

KIC7S04FU

AC ELECTRICAL CHARACTERISTICS ($C_L=15\text{pF}$, Input $t_r=t_f=6\text{ns}$, $V_{CC}=5\text{V}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta=25°C			UNIT
			MIN.	TYP.	MAX.	
Output Transition Time	t_{TLH} t_{THL}	-	-	5	10	ns
Propagation Delay Time	t_{pLH} t_{pHL}	-	-	7	15	ns

AC ELECTRICAL CHARACTERISTICS ($C_L=50\text{pF}$, Input $t_r=t_f=6\text{ns}$)

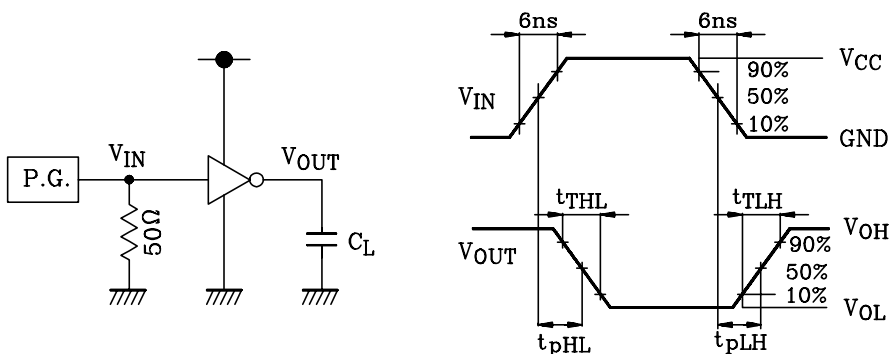
CHARACTERISTIC	SYMBOL	TEST CONDITION	V_{CC}	Ta=25°C			Ta=-40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t_{TLH} t_{THL}	-	2.0 4.5 6.0	- - -	50 14 12	125 25 21	- - -	155 31 26	ns
Propagation Delay Time	t_{pLH} t_{pHL}	-	2.0 4.5 6.0	- - -	48 12 9	100 20 17	- - -	125 25 21	ns
Input Capacitance	C_{IN}	-	-	-	5	10	-	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 1)	-	-	10	-	-	-	

Note 1 : C_{PD} defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit.)

Average operating current can be obtained by the equation hereunder.

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

SWITCHING CHARACTERISTICS TEST CIRCUIT



$I_{CC(opr)}$ TEST CIRCUIT

